

# CM50TU-24H

MEDIUM POWER SWITCHING USE  
INSULATED TYPE

## CM50TU-24H



- Ic ..... 50A
- VCES ..... 1200V
- Insulated Type
- 6-elements in a pack
- UL Recognized

Yellow Card No. E80276

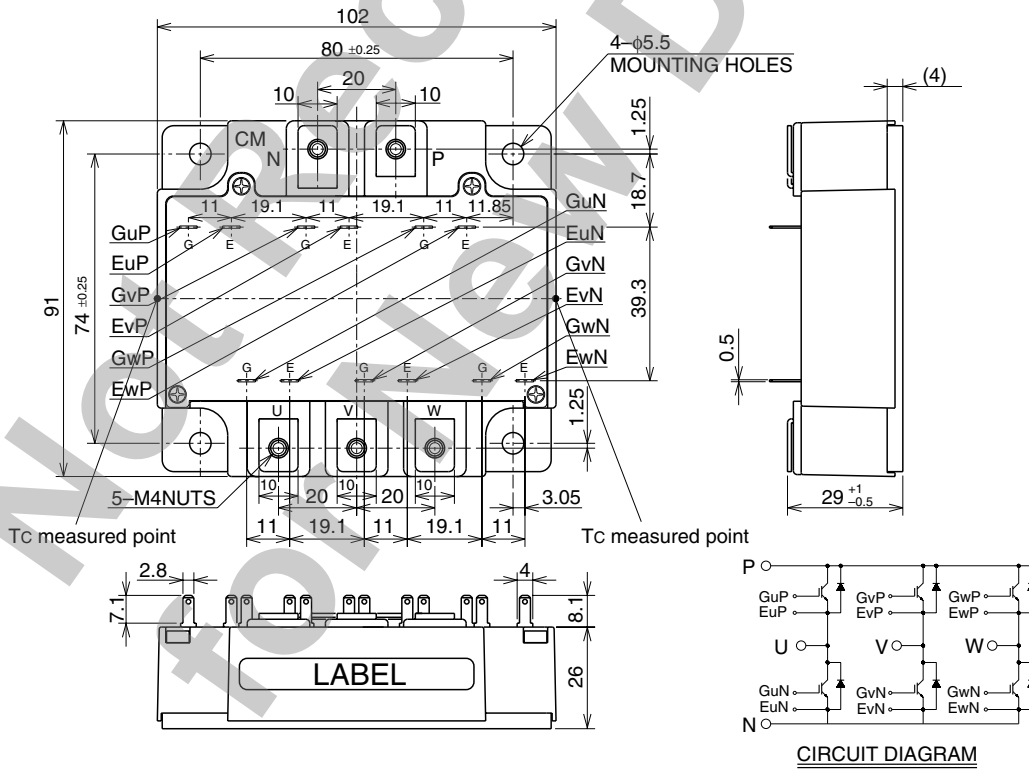
File No. E80271

## APPLICATION

UPS, NC machine, AC-Drive control, Servo, Welders

## OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



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**MAXIMUM RATINGS** (T<sub>j</sub> = 25°C, unless otherwise specified)

Symbol	Item	Conditions	Ratings	Unit
V <sub>CEs</sub>	Collector-emitter voltage	V <sub>GE</sub> = 0V	1200	V
V <sub>GES</sub>	Gate-emitter voltage	V <sub>CE</sub> = 0V	±20	V
I <sub>C</sub>	Collector current	T <sub>C</sub> = 25°C	50	A
I <sub>CM</sub>		Pulse (Note 1)	100	A
I <sub>E</sub> (Note 2)	Emitter current	T <sub>C</sub> = 25°C	50	A
I <sub>EM</sub> (Note 2)		Pulse (Note 1)	100	A
P <sub>C</sub> (Note 3)	Maximum collector dissipation	T <sub>C</sub> = 25°C	400	W
T <sub>j</sub>	Junction temperature	—	-40 ~ +150	°C
T <sub>stg</sub>	Storage temperature	—	-40 ~ +125	°C
V <sub>iso</sub>	Isolation voltage	Charged part to base plate, f = 60Hz, AC 1 minute	2500	Vrms
—	Mounting torque	Main terminals M4 screw	1.3 ~ 1.7	N·m
		Mounting M5 screw	2.5 ~ 3.5	N·m
—	Weight	Typical value	570	g

**ELECTRICAL CHARACTERISTICS** (T<sub>j</sub> = 25°C, unless otherwise specified)

Symbol	Item	Test Conditions	Limits			Unit
			Min	Typ	Max	
I <sub>CEs</sub>	Collector cutoff current	V <sub>CE</sub> = V <sub>CEs</sub> , V <sub>GE</sub> = 0V	—	—	1	mA
V <sub>GE(th)</sub>	Gate-emitter threshold voltage	I <sub>C</sub> = 5mA, V <sub>CE</sub> = 10V	4.5	6	7.5	V
I <sub>GES</sub>	Gate-leakage current	±V <sub>GE</sub> = V <sub>GES</sub> , V <sub>CE</sub> = 0V	—	—	0.5	µA
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>C</sub> = 50A, V <sub>GE</sub> = 15V (Note 4)	—	2.9	3.7	V
			—	2.85	—	
C <sub>ies</sub>	Input capacitance	V <sub>CE</sub> = 10V	—	—	7.5	nF
C <sub>oes</sub>	Output capacitance	V <sub>GE</sub> = 0V	—	—	2.6	nF
C <sub>res</sub>	Reverse transfer capacitance		—	—	1.5	nF
Q <sub>G</sub>	Total gate charge	V <sub>CC</sub> = 600V, I <sub>C</sub> = 50A, V <sub>GE</sub> = 15V	—	187	—	nC
t <sub>d(on)</sub>	Turn-on delay time	V <sub>CC</sub> = 600V, I <sub>C</sub> = 50A	—	—	80	ns
t <sub>r</sub>	Turn-on rise time	V <sub>GE</sub> = ±15V	—	—	200	ns
t <sub>d(off)</sub>	Turn-off delay time	R <sub>G</sub> = 6.3Ω	—	—	150	ns
t <sub>f</sub>	Turn-off fall time	Resistive load	—	—	350	ns
V <sub>EC</sub> (Note 2)	Emitter-collector voltage	I <sub>E</sub> = 50A, V <sub>GE</sub> = 0V	—	—	3.2	V
t <sub>rr</sub> (Note 2)	Reverse recovery time	I <sub>E</sub> = 50A,	—	—	300	ns
Q <sub>rr</sub> (Note 2)	Reverse recovery charge	die / dt = -100A / µs	—	0.28	—	µC
R <sub>th(j-c)Q</sub>	Thermal resistance (Note 5)	Junction to case, IGBT part (Per 1/6 module)	—	—	0.31	K/W
R <sub>th(j-c)R</sub>		Junction to case, FWDi part (Per 1/6 module)	—	—	0.7	K/W
R <sub>th(c-f)</sub>	Contact thermal resistance	Case to heat sink, conductive grease applied (Per 1/6 module) (Note 6)	—	0.11	—	K/W

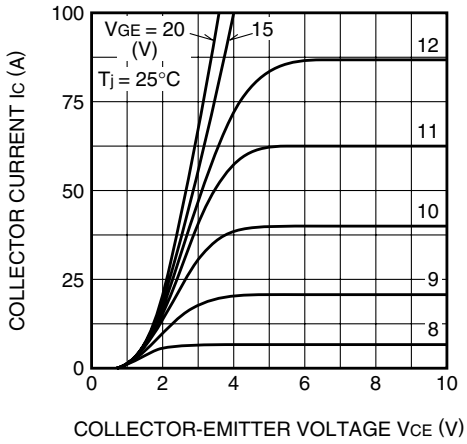
- Note 1. Pulse width and repetition rate should be such that the device junction temperature (T<sub>j</sub>) does not exceed T<sub>jmax</sub> rating.  
 2. I<sub>E</sub>, V<sub>EC</sub>, t<sub>rr</sub>, Q<sub>rr</sub> & die/dt represent characteristics of the anti-parallel, emitter-collector free-wheel diode.  
 3. Junction temperature (T<sub>j</sub>) should not increase beyond 150°C.  
 4. Pulse width and repetition rate should be such as to cause negligible temperature rise.  
 5. Case temperature (T<sub>C</sub>) measured point is shown in page OUTLINE DRAWING.  
 6. Typical value is measured by using thermally conductive grease of λ = 0.9[W/(m · K)].

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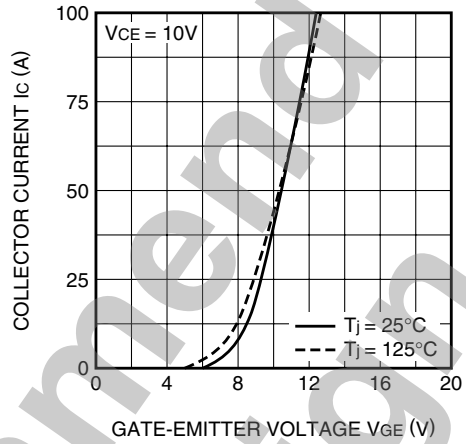
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PERFORMANCE CURVES

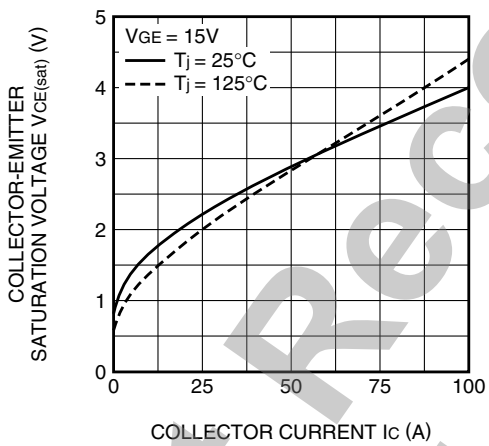
OUTPUT CHARACTERISTICS (TYPICAL)



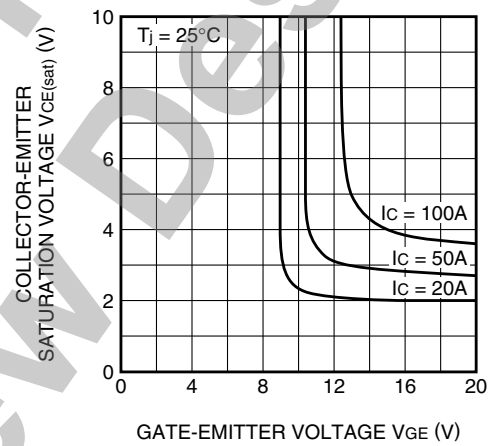
TRANSFER CHARACTERISTICS (TYPICAL)



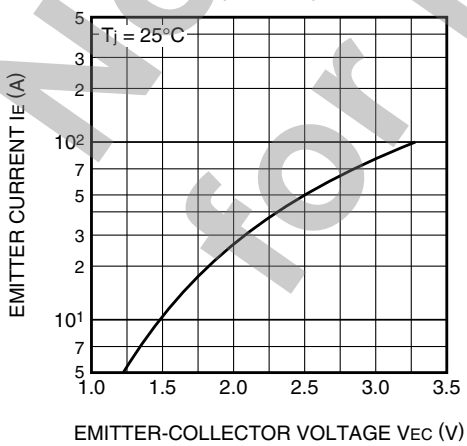
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



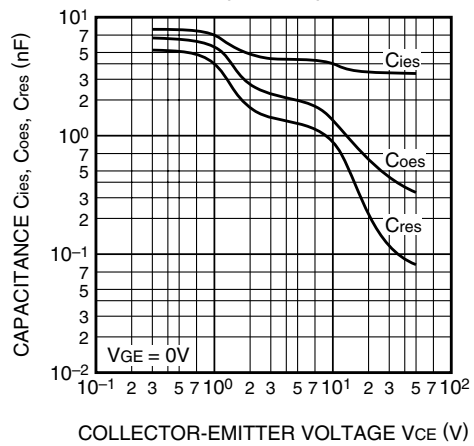
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



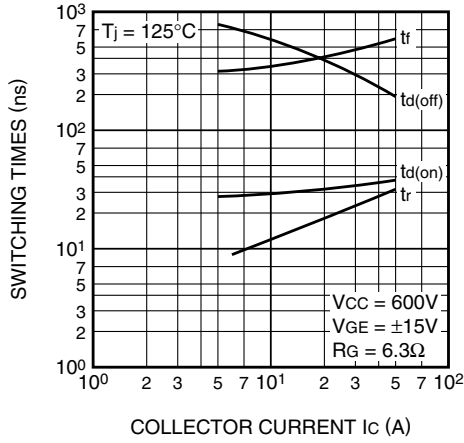
CAPACITANCE CHARACTERISTICS (TYPICAL)



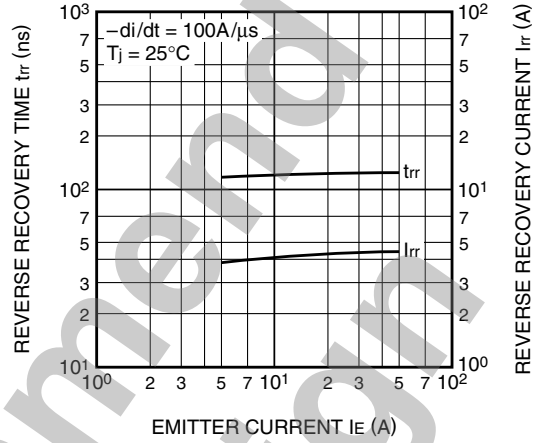
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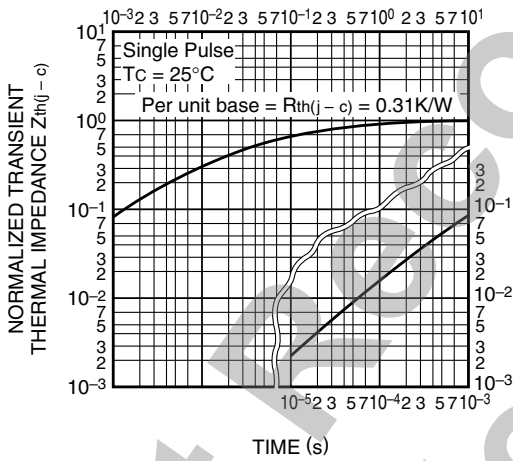
HALF-BRIDGE  
SWITCHING TIME CHARACTERISTICS  
(TYPICAL)



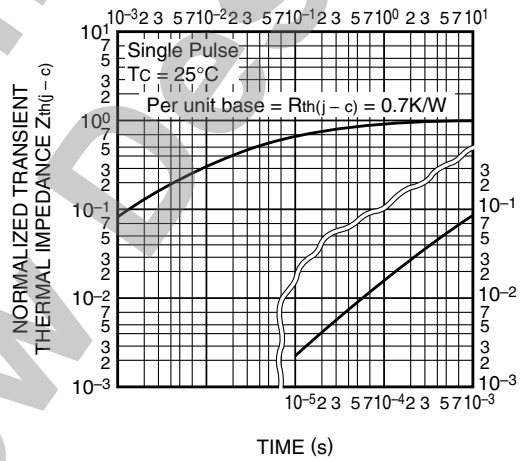
REVERSE RECOVERY CHARACTERISTICS  
OF FREE-WHEEL DIODE  
(TYPICAL)



TRANSIENT THERMAL  
IMPEDANCE CHARACTERISTICS  
(IGBT part)



TRANSIENT THERMAL  
IMPEDANCE CHARACTERISTICS  
(FWDi part)



GATE CHARGE CHARACTERISTICS  
(TYPICAL)

